

**SURFACE MOUNT
SCHOTTKY BARRIER RECTIFIERS**

REVERSE VOLTAGE - **20 to 60** Volts
FORWARD CURRENT - **3.0** Amperes

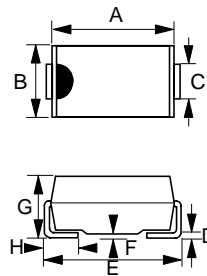
FEATURES

- For surface mounted applications
- Metal-Semiconductor junction with guardring
- Epitaxial construction
- Very Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case : Molded plastic
- Polarity : Indicated by cathode band
- Weight : 0.002 ounces, 0.064 grams

SMA



SMA		
DIM.	MIN.	MAX.
A	4.06	4.57
B	2.29	2.92
C	1.27	1.63
D	0.15	0.31
E	4.83	5.59
F	0.05	0.20
G	2.01	2.62
H	0.76	1.52
All Dimensions in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	B320A	B330A	B340A	B350A	B360A	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	20	30	40	50	60	V
Maximum RMS Voltage	VRMS	14	21	28	35	42	V
Maximum DC Blocking Voltage	VDC	20	30	40	50	60	V
Maximum Average Forward Rectified Current @TL =100°C	I(AV)	3.0					A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	IFSM	100					A
Maximum forward Voltage at 3.0A DC	VF	0.5		0.7			V
Maximum DC Reverse Current at Rated DC Blocking Voltage @TJ =25°C @TJ =100°C	IR	0.5			20		mA mA
Typical Junction Capacitance (Note 1)	CJ	250					pF
Typical Thermal Resistance (Note 2)	RθJL	10					°C/W
Typical Thermal Resistance (Note 3)	RθJA	50					°C/W
Operating Temperature Range	TJ	-55 to +125					°C
Storage Temperature Range	TSTG	-55 to +150					°C

NOTES : 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Thermal Resistance Junction to Lead.
3. Thermal Resistance Junction to Ambient.

REV. 2, 01-Dec-2000, KSHA05

